## Di-tert-butyl tin(IV) 2-pyridyl and 4,6-dimethyl-2-pyrimidyl thiolates: versatile single source precursors for the preparation of SnS nanoplatelets as anode material for lithium ion batteries

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## **Figure Captions**

Figure S1 <sup>1</sup>H NMR spectrum of [<sup>1</sup>Bu<sub>2</sub>Sn(Spy)<sub>2</sub>] (1) acquired in CDCl<sub>3</sub>.

Figure S2  ${}^{13}C{}^{1H}$  NMR spectrum of  $[{}^{1}Bu_2Sn(Spy)_2]$  (1) acquired in CDCl<sub>3</sub>.

Figure S3  $^{119}$ Sn{ $^{1}H$ } NMR spectrum of [ $^{1}Bu_{2}$ Sn(Spy)<sub>2</sub>] (1) acquired in CDCl<sub>3</sub>.

Figure S4 <sup>1</sup>H NMR spectrum of [<sup>1</sup>Bu<sub>2</sub>SnCl(Spy)] (2) acquired in CDCl<sub>3</sub>.

Figure S5  ${}^{13}C_{1}^{(1}H$  NMR spectrum of [ ${}^{t}Bu_{2}SnCl(Spy)$ ] (2) acquired in CDCl<sub>3</sub>.

Figure S6 <sup>119</sup>Sn{<sup>1</sup>H} NMR spectrum of ['Bu<sub>2</sub>SnCl(Spy)] (2) acquired in CDCl<sub>3</sub>.

Figure S7 <sup>1</sup>H NMR spectrum of  $[{}^{t}Bu_{2}SnCl(SpymMe_{2})]$  (3) acquired in CDCl<sub>3</sub>.

Figure S8  ${}^{13}C_{\{}^{1}H_{\}}$  NMR spectrum of [ ${}^{1}Bu_2SnCl(SpymMe_2)$ ] (3) acquired in CDCl<sub>3</sub>.

Figure S9 <sup>119</sup>Sn{<sup>1</sup>H} NMR spectrum of [ ${}^{1}Bu_{2}SnCl(SpymMe_{2})$ ] (3) acquired in CDCl<sub>3</sub>.

Figure S 10 Disorder molecular structure of  $[{}^{t}Bu_{2}Sn(Spy)_{2}]$  (1) mirrored through (202) plane.

Figure S11 EDS spectrum of SnS nanoplatelets prepared from the thermolysis of  $[{}^{t}Bu_{2}Sn(Spy)_{2}]$  (1) in *OAm*.

Figure S12 EDS spectrum of SnS nanoplatelets prepared from the thermolysis of  $[Bu_2SnCl(Spy)]$  (2) in OAm.

Figure S13 EDS spectrum of SnS nanoplatelets prepared from the thermolysis of  $[^{1}Bu_{2}SnCl(SpymMe_{2})]$  (3) in OAm.

Figure S14 XPS spectrum of SnS nanoplatelets prepared from the thermolysis of ['Bu<sub>2</sub>SnCl(SpymMe<sub>2</sub>)] (3) in OAm (a) survey scan, (b) Sn 3d region, (c) S 2p region.

Figure S15 The elemental imaging of SnS nanoplatelets obtained by the thermolysis of (a)  $[{}^{1}Bu_{2}Sn(Spy)_{2}]$  (1), (b)  $[{}^{1}Bu_{2}Sn(Cl)(Spy)]$  (2) and (c)  $[{}^{1}Bu_{2}Sn(Cl)(SpymMe_{2})]$  (3), respectively in OAm. Figure S16 The SAED patterns of SnS nanoplatelets obtained by the thermolysis of (a)  $[{}^{1}Bu_{2}Sn(Spy)_{2}]$  (1), (b)  $[{}^{1}Bu_{2}Sn(Cl)(Spy)]$  (2) and (c)  $[{}^{1}Bu_{2}Sn(Cl)(SpymMe_{2})]$  (3), respectively in OAm. Figure S17 pXRD spectra of orthorhombic phase of SnS thin films deposited on (a) glass and (b) silicon substrate by the AACVD of  $[{}^{L}Bu_{2}Sn(Spy)_{2}]$  (1) at 400 °C for 1 h. (c) represents the standard SnS XRD patter (JCPDS file no. 39-0354).

Figure S18 AFM images of micro regions,  $30.0 \times 30.0$ ,  $10.0 \times 10.0$  and  $5.0 \times 5.0 \ \mu\text{m}^2$  SnS thin film deposited on (a,b,c) silicon and (d,e,f) glass substrate by the AACVD of [ ${}^{t}Bu_2Sn(Spy)_2$ ] (1) at 400 °C for 1 h.

Figure S19 Estimation of lithium diffusion coefficient of SnS nanoplatelets obtained from the thermolysis of  $[{}^{1}Bu_{2}Sn(Spy)_{2}]$  (1). Linear relation between Z' and square root of frequency. The warburg constant ( $\sigma$ ) could be obtained from the slop of the plot.

Figure S20 Electrochemical performance of SnS anode after removal of capping agent.



Figure S1 <sup>1</sup>H NMR spectrum of  $[{}^{t}Bu_{2}Sn(Spy)_{2}]$  (1) acquired in CDCl<sub>3</sub>.



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Substrate	Micro-area scanned (µm <sup>2</sup> )	Average roughness (nm)
Silicon	30.0 × 30.0	175
	$10.0 \times 10.0$	86.9
	5.0×5.0	31.3
Glass	30.0 × 30.0	178.9
	$10.0 \times 10.0$	133.7
	5.0×5.0	47.4

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